



YOUSHANG SEMICONDUCTOR

设计研发新型功率器件

各类小信号开关

中低压及高压大电流等场效应管

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Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

Features

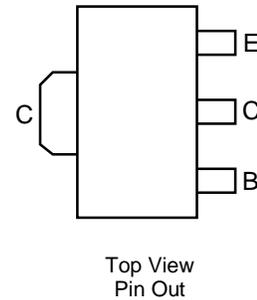
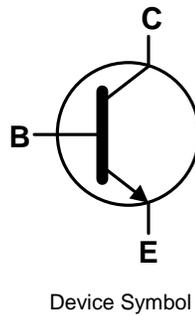
- $BV_{CEO} > 20V$
- $I_C = 1A$ High Continuous Current
- Low Saturation Voltage $V_{CE(sat)} < 500mV @ 1A$
- Complementary PNP type: NK-BCX6925

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Finish Leads. Solderable per MIL-STD-202 Method 208 **e3**
- Weight: 0.055 grams (Approximate)

Application

- Power MOSFET Gate Driving
- Low Loss Power Switching



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 25 | V |
| Collector-Emitter Voltage | V _{CEO} | 20 | V |
| Emitter-Base Voltage | V _{EBO} | 5 | V |
| Continuous Collector Current | I _C | 1 | A |
| Peak Pulse Current | I _{CM} | 2 | A |
| Base Current | I _B | 100 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

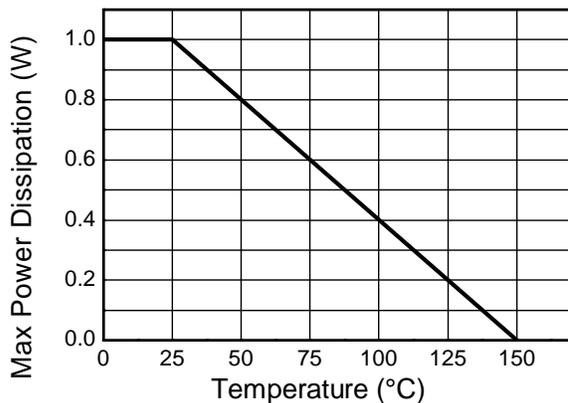
| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Collector Power Dissipation | P _D | 1 | W |
| Thermal Resistance, Junction to Ambient Air (Note 6) | R _{θJA} | 125 | °C/W |
| Thermal Resistance, Junction to Leads (Note 7) | R _{θJL} | 10.01 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -65 to +150 | °C |

ESD Ratings (Note 8)

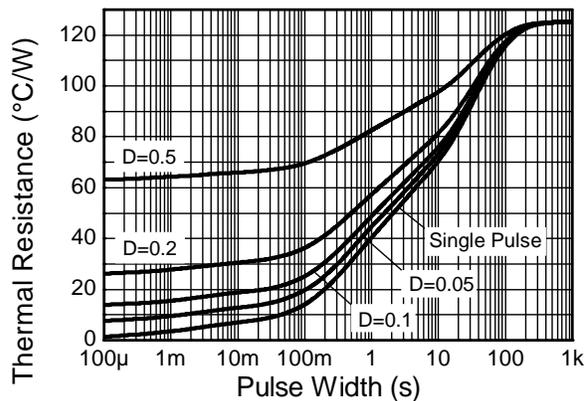
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|---------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | ≥ 8,000 | V | 3B |
| Electrostatic Discharge - Machine Model | ESD MM | ≥ 400 | V | C |

- Notes:
6. For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.
 7. Thermal resistance from junction to solder-point (on the exposed collector pad).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

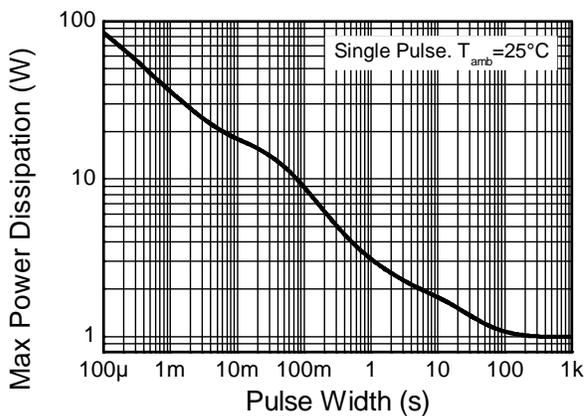
Thermal Characteristics and Derating Information



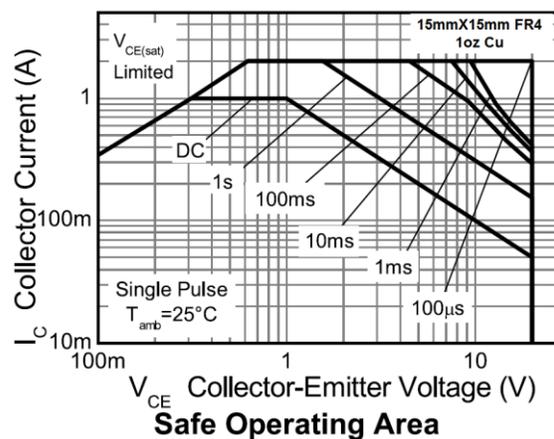
Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation

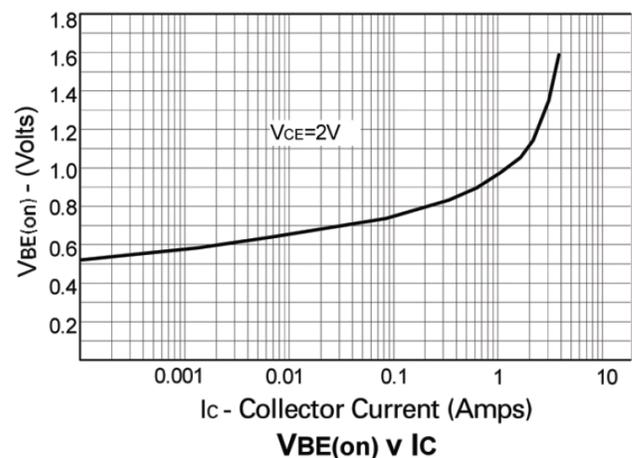
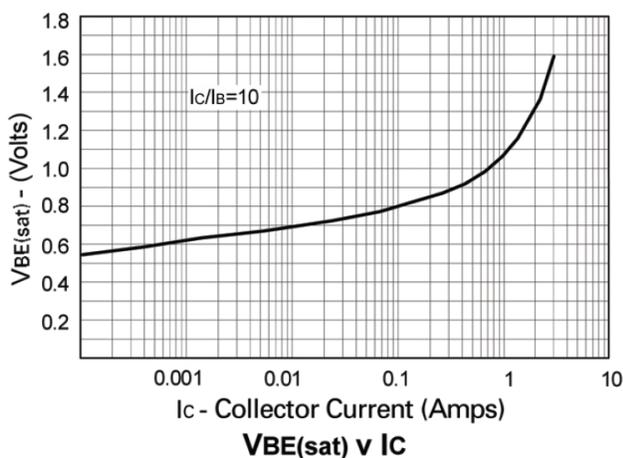
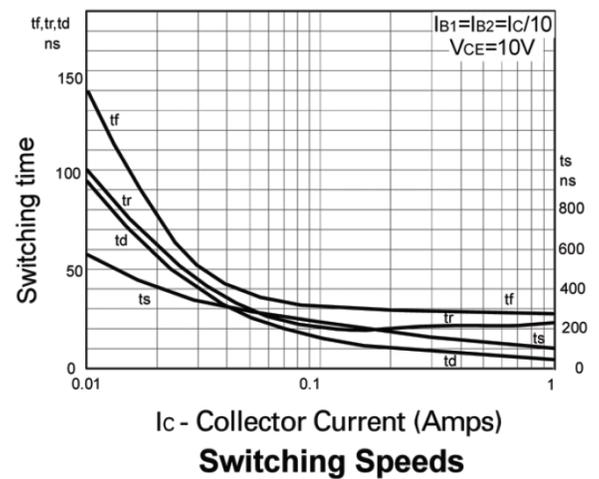
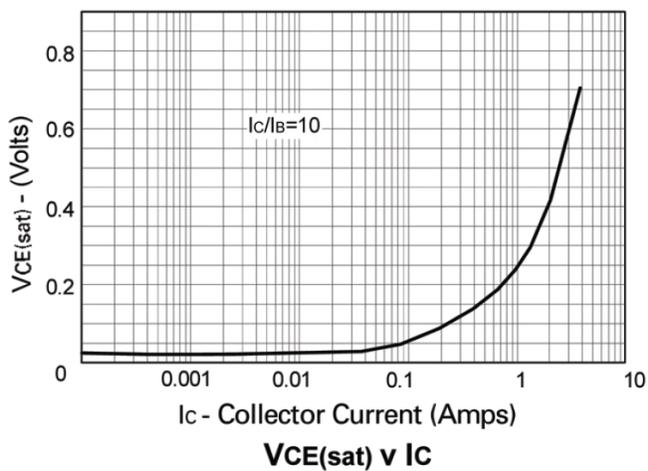


Safe Operating Area

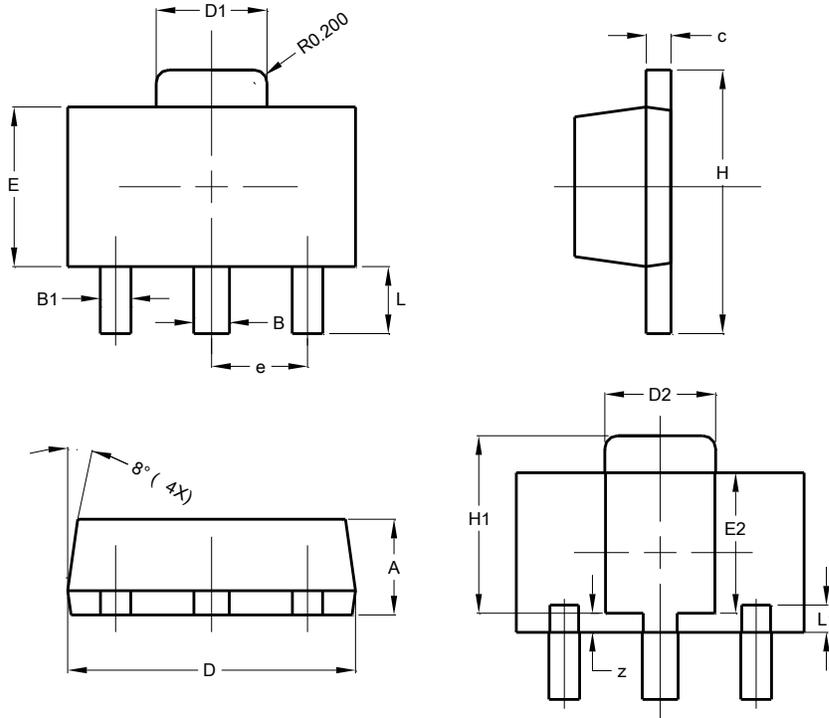
Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ. | Max | Unit | Test Condition |
|---|---------------|-----------------|---------------|---------------|---------------------|--|
| Collector-Base Breakdown Voltage | BV_{CBO} | 25 | - | - | V | $I_C = 100\mu\text{A}$ |
| Collector-Emitter Breakdown Voltage (Note 9) | BV_{CEO} | 20 | - | - | V | $I_C = 10\text{mA}$ |
| Emitter-Base Breakdown Voltage | BV_{EBO} | 5 | - | - | V | $I_E = 100\mu\text{A}$ |
| Collector Cutoff Current | I_{CBO} | - | - | 100 10 | nA μA | $V_{CB} = 25\text{V}$ $V_{CB} = 25\text{V}, T_A = +125^\circ\text{C}$ |
| Emitter Cutoff Current | I_{EBO} | - | - | 100 | nA | $V_{EB} = 5\text{V}$ |
| DC current transfer Static Ratio (Note 9) | h_{FE} | 50 160 60 | - 250 - | - 400 - | - | $I_C = 5\text{mA}, V_{CE} = 10\text{V}$ $I_C = 500\text{mA}, V_{CE} = 1\text{V}$ $I_C = 1\text{A}, V_{CE} = 1\text{V}$ |
| Collector-Emitter Saturation Voltage (Note 9) | $V_{CE(sat)}$ | - | - | 0.5 | V | $I_C = 1\text{A}, I_B = 100\text{mA}$ |
| Base-Emitter Turn-on Voltage (Note 9) | $V_{BE(on)}$ | - | - | 1.0 | V | $I_C = 1\text{A}, V_{CE} = 1\text{V}$ |
| Transitional Frequency | f_T | 100 | - | - | MHz | $I_C = 100\text{mA}, V_{CE} = 5\text{V}, f = 100\text{MHz}$ |
| Output Capacitance | C_{obo} | - | - | 25 | pF | $V_{CB} = 10\text{V}, f = 1\text{MHz}$ |

Note: 9. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

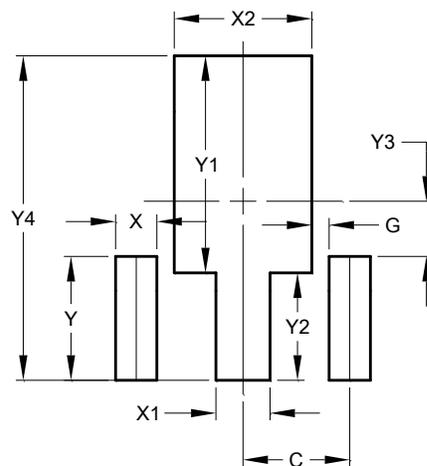
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)


Package Outline Dimensions



| SOT89 | | | |
|-----------------------------|-------|-------|-------|
| Dim | Min | Max | Typ |
| A | 1.40 | 1.60 | 1.50 |
| B | 0.50 | 0.62 | 0.56 |
| B1 | 0.42 | 0.54 | 0.48 |
| c | 0.35 | 0.43 | 0.38 |
| D | 4.40 | 4.60 | 4.50 |
| D1 | 1.62 | 1.83 | 1.733 |
| D2 | 1.61 | 1.81 | 1.71 |
| E | 2.40 | 2.60 | 2.50 |
| E2 | 2.05 | 2.35 | 2.20 |
| e | - | - | 1.50 |
| H | 3.95 | 4.25 | 4.10 |
| H1 | 2.63 | 2.93 | 2.78 |
| L | 0.90 | 1.20 | 1.05 |
| L1 | 0.327 | 0.527 | 0.427 |
| z | 0.20 | 0.40 | 0.30 |
| All Dimensions in mm | | | |

Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 1.500 |
| G | 0.244 |
| X | 0.580 |
| X1 | 0.760 |
| X2 | 1.933 |
| Y | 1.730 |
| Y1 | 3.030 |
| Y2 | 1.500 |
| Y3 | 0.770 |
| Y4 | 4.530 |